

WSJM65R120X Super-Junction Power MOSFET

Rev.01 - 23 February 2024

Product data sheet

1. General description

WSJM65R120X is a high voltage N-channel MOSFET in TO220F package, which utilizes the advanced super-junction technology to provide superior FOM $R_{DS(on)} * Q_g$ among silicon based MOSFETs. It is particularly suitable for applications require extreme high efficiency and power density.



2. Features and benefits

- Superior FOM R_{DS(on)} * Q_g
- Extremely low switching loss
- 100% avalanche tested

3. Applications

high efficiency power supplies

4. Quick reference data

Table 1. Qu	lick reference data						
Symbol	Parameter	Conditions	Notes	s Values			Unit
Absolute	maximum rating						
V_{DS}	drain-source voltage			650		V	
V_{GS}	gate-source voltage				±30		V
I _D	continuous drain current	T _h = 25 °C	[1]		30		А
P _{tot}	power dissipation	T _h = 25 °C		36		W	
Tj	junction temperature			-55 to 150		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics	·	•			·	
$R_{\text{DS(on)}}$	drain-source on-state resistance	V _{GS} = 10 V, I _D = 15 A		-	105	120	mΩ
Dynamic of	characteristics	·					
Q _{G(tot)}	total gate charge	$I_{D} = 15 \text{ A}; V_{DS} = 400 \text{ V}; V_{GS} = 10 \text{ V}$		-	54	-	nC
E _{oss}	coss stored erergy	V_{GS} = 0 V; V_{DS} = 0 to 400 V		-	6.6	-	μJ

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	G	gate	mb	D			
2	D	drain					
3	S	source					
mb	n.c.	mounting base; isolated		svm300 S			

6. Ordering information

Table 3. Ordering information							
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date	
WSJM65R120X	TO220F	WSJM65R120XQ	Tube	50	SOT186A	14-Nov-2013	

7. Marking

Table 4. Marking codes					
Marking codes					
WSJM 65P120Y					
	U				

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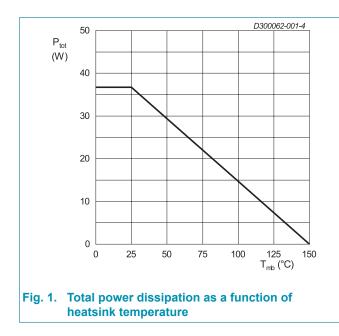
8. Limiting values

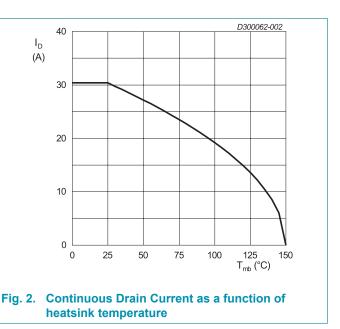
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V _{DS}	drain-source voltage			650	V
V _{GS}	gate-source voltage			±30	V
I _D	continuous drain current	T _h = 25 °C	[1]	30	А
		T _h = 100 °C	[1]	19	А
I _{DM}	pulsed drain current	T _h = 25 °C		120	А
P _{tot}	power dissipation	T _h = 25 °C		36	W
E _{AS}	single pulse drain-to- source avalanche	I_{AS} = 8.4 A; R _{GS} = 25 Ω; V _{DD} = 50 V; T _j = 25 °C		352	mJ
E _{AR}	repetitive avalanche energy	I_{AS} = 8.4 A; R _{GS} = 25 Ω; V _{DD} = 50 V; T _j = 25 °C		1.48	mJ
I _{AS}	avalanche current, single pulse			8.4	A
dv/dt	MOSFET dv/dt ruggedness			50	V/ns
dv/dt	reverse diode dv/dt			10	V/ns
dI _F /dt	maximum diode commutation speed			500	A/µs
T _{stg}	storage temperature			-55 to 150	°C
Tj	junction temperature			-55 to 150	°C

[1] Limited by maximum junction temperature, equivalent to TO220.

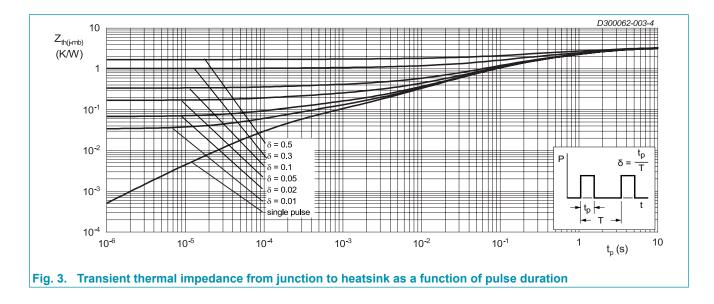




9. Thermal & Mechanical characteristics

Table 6. Thermal & Mechanical characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink			-	2.6	3.4	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air		-	60	-	K/W



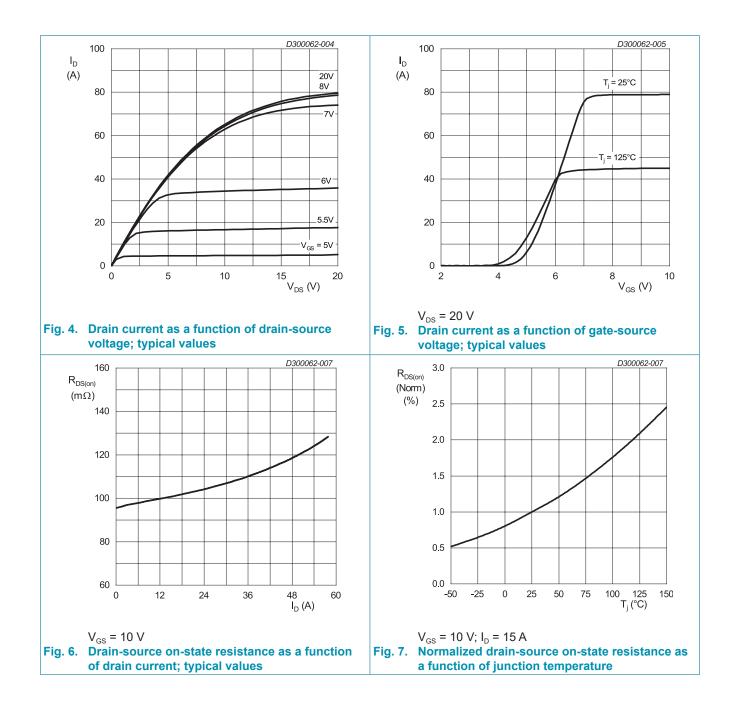
10. Characteristics

Table 7. Characteristics

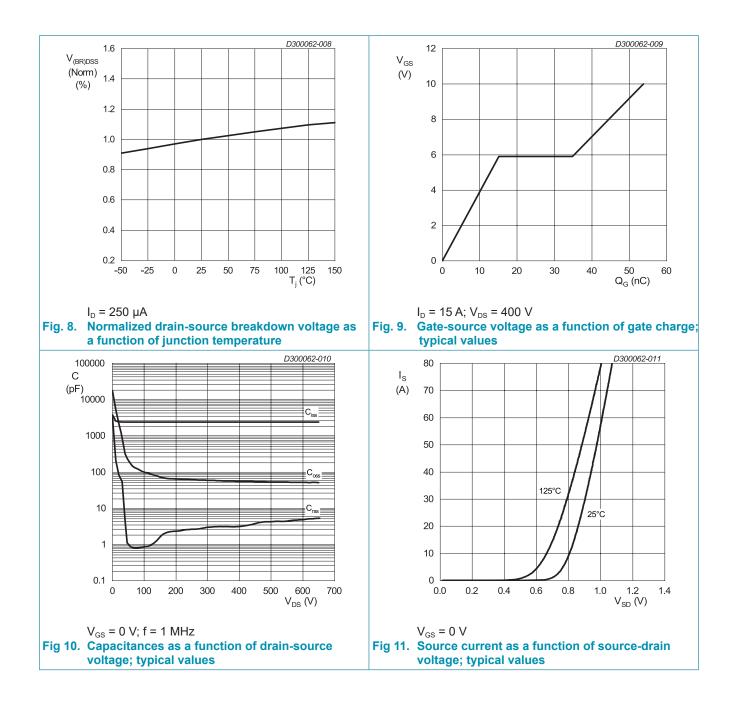
T_j = 25 °C unless otherwise noted

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	I_{D} = 250 µA; V_{GS} = 0 V		650	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	I_{D} = 250 µA; V_{DS} = V_{GS}		2.5	-	4.5	V
I _{DSS}	drain leakage current	$V_{DS} = 650 \text{ V}; V_{GS} = 0 \text{ V}$		-	-	1	μA
		$V_{DS} = 650 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 125 \text{ °C}$		-	-	10	μA
I _{GSS}	gate leakage current	$V_{GS} = \pm 30 \text{ V}; V_{DS} = 0 \text{ V}$		-	-	±100	nA
$R_{\text{DS(on)}}$	drain-source on-state resistance	V_{GS} = 10 V; I _D = 15 A		-	105	120	mΩ
R _G	gate resistance	f = 1 MHz		-	1.7	-	Ω
Dynamic	characteristics						
Q _{G(tot)}	total gate charge	I_{D} = 15 A; V_{DS} = 400 V; V_{GS} = 10 V		-	54	-	nC
Q _{GS}	gate-source charge			-	15	-	nC
Q _{GD}	gate-drain charge			-	20	-	nC
C _{iss}	input capacitance	V _{DS} = 400 V; V _{GS} = 0 V; f = 1 MHz		-	2402	-	pF
C _{oss}	output capacitance			-	56	-	pF
C _{rss}	reverse transfer capacitance			-	3.4	-	pF
C _{o(er)}	effective output capacitance, energy related	V_{GS} = 0 V; V_{DS} = 0 to 400 V		-	83	-	pF
C _{o(tr)}	effective output capacitance, time related			-	415	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 400 \text{ V}; V_{GS} = 10 \text{ V}; R_G = 10 \Omega;$		-	48	-	ns
t _r	rise time	I _D = 15 A		-	11	-	ns
t _{d(off)}	turn-off delay time			-	97	-	ns
t _f	fall time			-	11	-	ns
Source-d	rain diode						
V _{SD}	source-drain voltage	V _{GS} = 0 V; I _S = 15 A		-	0.8	1.1	V
ls	body-diode continuous current	T _h = 25 °C		-	-	30	A
t _{rr}	reverse recovery time	V_{R} = 400 V; I _F = 15 A; dI _F /dt = 100 A/µs		-	376	-	ns
Q _{rr}	reverse recovered charge			-	6.3	-	μC
I _{rrm}	reverse recovery current			-	32	-	А

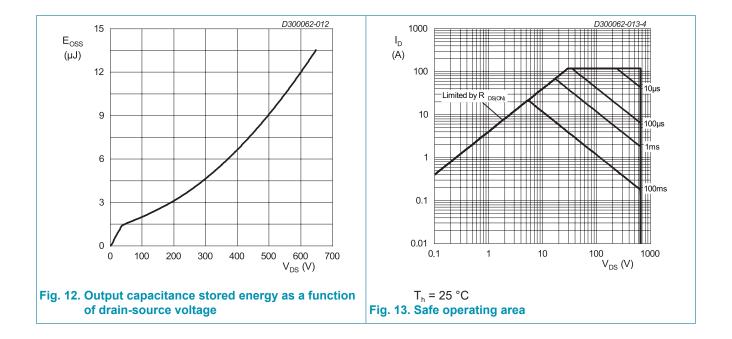
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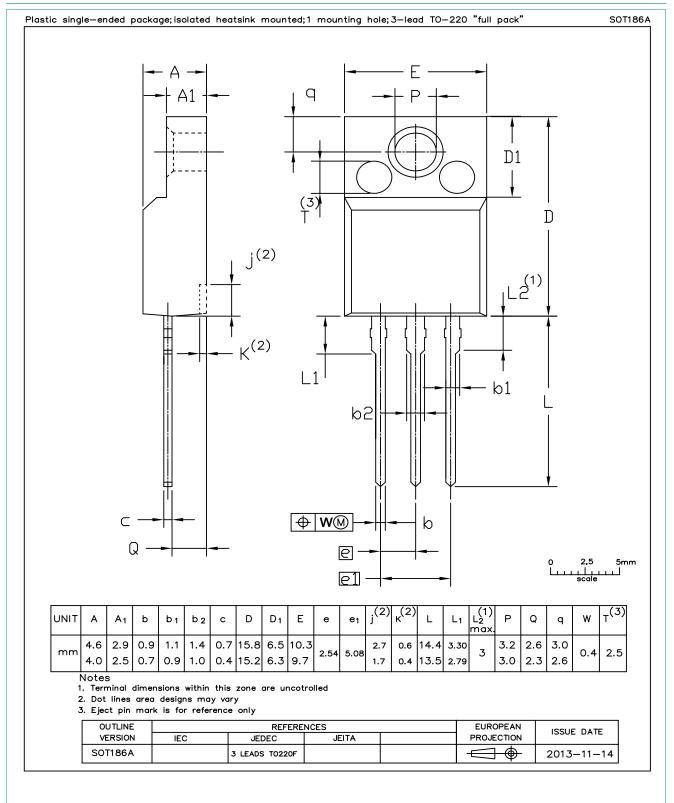


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11. Package outline



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Product data sheet

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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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